

Optical Characterization in Industry, National Labs, and Academia

- 1. Industrial Materials Characterization using Spectroscopic techiques
- 2. Multiuser facilities at National Labs
- 3. University Optical Labs

Major suppliers of Spectroscopic Equipment (solutions)

JY Horiba

Bruker / Siemens

Sopra

Philips

Accent-Biorad

Spectra-Physics

Parts: Edmund Optics and CVI

Optical Characterization in Industry:

Materials and device structure characterization in a production line

- 1. Thin films, coatings, multilayers
- 2. Composition and strain
- 3. Conductivity / resistance
- 4. Nanotechnology and nanoscale characterization
- 5. In situ characterization (on fly)

Issues:

Maintanence

Speed

Interpretation and models

- 1. FT-IR Reflectivity and Transmission (IV)
- 2. Raman Scattering (III-V)
- 3. Spectroscopic ellipsometry (IV)
- 4. Photoluminescence (III-V)
- 5. Micro-photoluminescence (III-V,IV)
- 6. X-ray diffraction (III-V)
- 7. X-ray fluorescence
- 8. E-beam spectroscopy
- 9. Imaging vs. Analythical characterization

Optical Characterization in National Labs New materials and ideas

- 1. Emergent materials
- 2. New instrumentation / new
 - techniques
- 3. Bio-optics
- 4. Nanomaterials
- 5. In situ characterization

- 1. Micro FT-IR Reflectivity and Transmission
- 2. Surface-enhanced Raman Scattering
- 3. Far-IR Spectroscopic ellipsometry (IV)
- 4. Near-field Photoluminescence (III-V)
- 5. Nano-scale X-ray diffraction (III-V)
- 6. X-ray fluorescence / X-ray standing waves
- 7. E-beam bio-imaging

Goals: unique experiments with emergent materials

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Examples of Optical Characterization in National Labs New materials and ideas

Co-Localization of β-Amyloid Deposits and Metal Accumulation in Alzheimer's Disease

Beamline:

NSLS: U10B, X26A, X27A APS: 13ID. 18ID

Technique:

X-ray Fluorescence Microprobe

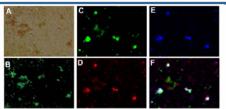
Researchers:

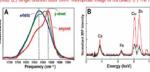
Q. Wang, T. P. Telivala, R. Smith, A. Lanzirotti, L. M. Miller (BNL), J. Miklossy (UBC)

Publication:

Lisa M. Miller, Qi Wang, Tejas P. Telivala, Randy J. Smith, Antonio Lanzirotti and Judith Miklossy. Journal of Structural Biology, 155(1): 30-3, 2006

(AD) is characterized by the misfoldina and plaque-like accumulation of a naturally occurring protein, amyloid beta (AB) in the brain. This misfolding process has been associated with the binding of metal ions such as Fe, Cu, and Zn in vitro. The secondary structure of the amyloid plaques is imaged in situ using Fourier transform infrared microspectroscopy (FTIRM). The metal ion accumulation in the identical brain tissue is detected by synchrotron x-ray fluorescence (XRF) microprobe synchrotron. The aim is to spatially correlate the in situ metal distribution with the characteristic protein structure changes of amyloid plaques.





Biochim. Biophys.

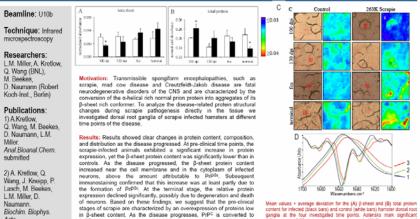
1758: 948-59 (2006).

for early TSE diagnosis and treatment.

Examples of Optical Characterization in National Labs

New materials and ideas

Changes in Protein Structure and Distribution Observed at Pre-Clinical Stages during Scrapie Pathogenesis



tion for the (A) β-sheet and (B) total protein content for infected (black bars) and control (white bars) hamster dorsal roo ganglia at the four investigated time points. Asterisks mark significant differences (p<0.05) between scrapie and control. (C) Photomicrographs of PrP^{c} , along with the conversion or replacement of other α -helical-rich proteins by β -sheet proteins. The dramatic changes in protein content consensions (provide) enteriors scrape and corrors (c) Procommorpopiets or unstaned cryp-sections (1st and 4et columns) and corresponding FTRMI images (2nd and 4th columns) of the (p-sheet distribution for corror (left)) and indicated inptly against a different time portras. Areas entiting externelly level (p-sheet as 100 gis are indicated by arrowheads. (ii) Original and 2nd derivative spectra of areas indicated by arrowheads. (iii) Original and 2nd spectra of areas indicated by numbers in the chemical maps. Red sparse in photomicrographs. 10x10 primitives. and structure at pre-clinical time points emphasizes the need for identifying protein changes involved in early pathogenesis, which are important for understanding the disease and may provide a mechanism

Examples of Optical Characterization in National Labs

New materials and ideas

Compositional Changes Observed in the Calcified Cartilage and Subchondral Bone in a Monkey Model of Osteoarthritis

Beamline: U10B

Technique: Infrared Microspectroscopy

Researchers:

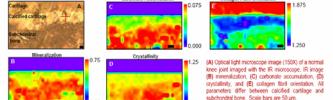
Meghan E. Ruppel, Lisa M. Miller (BNL-NSLS); Cathy S. Carlson (Univ. of Minnesota)

Publications:

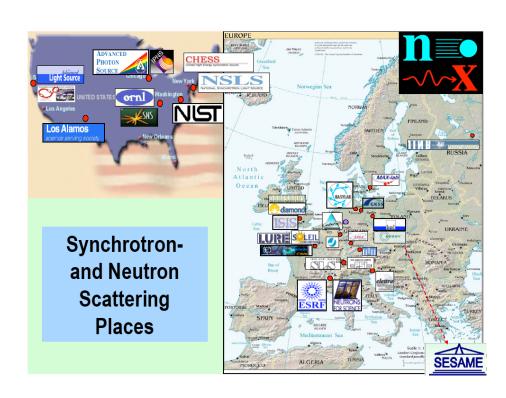
L.M. Miller, J. Tetenbaum Novatt, D. Hamerman, C.S. Carlson. Bone, 35 (2): 498-506 (2004)

M.E. Ruppel, C.S. Carlson, L.M. Miller. In preparation

Motivation: Osteoarthritis (OA) can be a debilitating disease that is characterized by fibrillation and calcification of the articular cartilage and thickening of the subchondral bone. In the present study, the chemical makeup of both the calcified cartilage and subchondral bone were studied in a primate model of OA. Mid-coronal sections of proximal tibia from cynomolgus monkeys were examined. Synchrotron-assisted Fourier transform infrared microscopy (FTIRM) was used to determine the level of mineralization (mineral/protein ratio), carbonate accumulation (carbonate/phosphate ratio), and collagen fibril orientation (amide I/II band ratio) as a function of tissue compartment and OA severity



Results: Results showed that the level of mineralization (p=0.0431) and carbonate accumulation (p<0.0001) were significantly higher in subchondral bone when compared to calcified cartilage. The amide I/II ratio was also significantly different between the subchondral bone and calcified cartilage, suggesting differences in collagen organization between the two tissue compartments. As a function of OA severity, the mineralization level of the calcified cartilage increased (p=0.0037), but the subchondral bone remained unchanged. The collagen orientation was not affected by OA severity. Compositional differences between calcified cartilage and subchondral bone suggest subchondral bone is older, more mature tissue. Additionally compositional changes that are observed as a function of OA severity are consistent with the progression of a "mineralization front" where endochondral ossification occurs and calcified cartilage is replaced by subchondral bone. These findings indicate that calcified cartilage and subchondral bone have distinctly different collagen structure and mineral composition that are affected by OA severity and could increase stress on the afflicted joints



How to get an access to multi-user facilities at National Labs Need ideas

- Select Facility (Synchrotron, Observatiry, Neutron source, ...)
- Register as a user
- Write a proposal. Remember that Proposals become "Public Information"
- Schedule time for experiment
- Pass safety training
- Arrive to Facility and carry out experiments exactly how it is described in your proposal
- Write a paper
- Start this process over

HW: write a 2-page proposal for any experiment Follow guidelines for proposal writing at any Facility, e.g, CHESS

OUTLINE

X-ray Spectroscopy

X-ray radiation. Sources of X-rays, Detection of X-rays

Primary techniques: Fluorescence, Diffraction, Scattering

Instrumentation: Diffractometers, detectors

Applications

Neutrons Spectroscopy

Sources, Detectors

Techniques: diffraction and Inelastic scattering

Instrumentation and Applications

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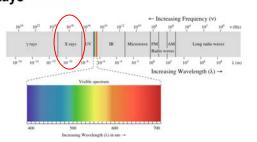
Discovery of X-rays

Wilhelm Conrad Röntgen 1845-1923





1895: Discovery of X-Rays



Nobel Prizes for Research with X-Rays

1901 W. C. Röntgen in Physics for the discovery of x-rays.

1914 M. von Laue in Physics for x-ray diffraction from crystals.

1915 W. H. Bragg and W. L. Bragg in Physics for crystal structure determination.

1917 C. G. Barkla in Physics for characteristic radiation of elements.

1924 K. M. G. Siegbahn in Physics for x-ray spectroscopy.

1927 A. H. Compton in Physics for scattering of x-rays by electrons.

1936 P. Debye in Chemistry for diffraction of x-rays and electrons in gases.

1962 M. Perutz and J. Kendrew in Chemistry for the structure of hemoglobin.

1962 J. Watson, M. Wilkins, and F. Crick in Medicine for the structure of DNA.

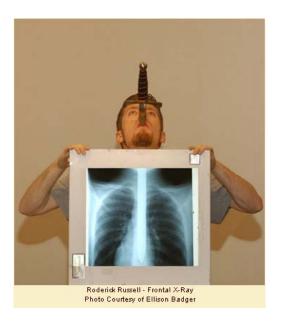
1979 A. McLeod Cormack and G. Newbold Hounsfield in Medicine for computed axial tomography.

1981 K. M. Siegbahn in Physics for high resolution electron spectroscopy.

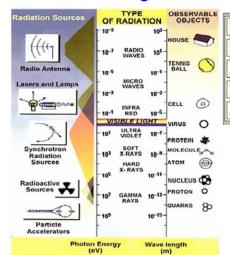
1985 H. Hauptman and J. Karle in Chemistry for direct methods to determine x-ray structures.

1988 J. Deisenhofer, R. Huber, and H. Michel in Chemistry for the structures of proteins that are crucial to photosynthesis.

OTHER USE of X-RAYS



Wavelength and the size of observable objects



Scatterers Electron-beam (spacings) (typical dimension (3.7 pm for 100 keV) Ink dots in newsprint Light (520 nm for green) (0.1 mm) Raindrops X-rav (0.154 nm for Cu Ka) Row of parked cars Sound Precipitates in alloys (1.26 m at middle C) Thermal radiation Atoms in crystals (0.1 m typical)

The most important information arises when the wavelength of the radiation is similar to, or smaller than, the size of the spacing between the objects being studied. Wavelength

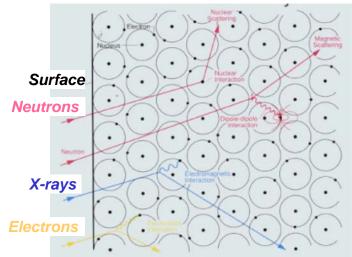
Cobject Size

Angstroms
for Condensed

Matter Research

 $\lambda[\text{Å}] = \frac{12.398}{E_{\text{ph}}[\text{keV}]}$

Interaction of Electrons, X-rays, and Neutrons with matter

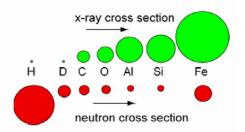


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- Neutrons interact with atomic nuclei via very short range (~fm) forces.
- Neutrons also interact with unpaired electrons via a magnetic dipole interaction.

Neutrons vs. x-rays

- Whereas neutrons interact primarily by the strong force, x-rays interact by scattering from electrons.
- The interaction of neutrons with nuclei has the advantage that neutrons can see small atoms (the scattering power for neutrons varies almost randomly for neutrons, as compared to x-rays where it goes like Z²).
- Neutrons are therefore wellsuited to study low-Z atomic structures.

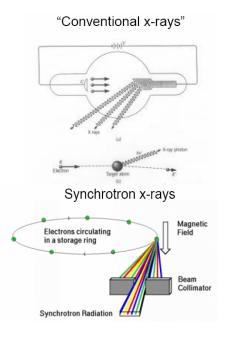


This shows how the cross-section, which is related to the size of the Bragg peaks, varies for x-rays (where it increases for increasing size of the atoms, and therefore the number of electrons), compared to neutrons (where it is governed by nuclear interactions – almost random).

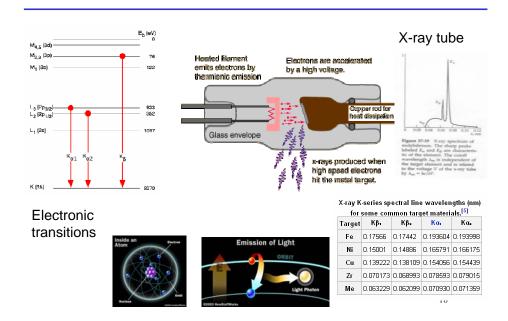
Sources of X-rays

- X-rays in conventional labs are usually produced by the inverse photoelectric effect (ie. Electrons are accelerated to a target metal, and when they slow down they produce x-ray radiation).
- However, you can produce extremely bright x-rays from synchrotron radiation – accelerate charged particles to very high speeds, and then bend their trajectories using electric and magnetic fields.
- At every 'bend', the charged particles are accelerated, and they give off x-ray radiation.

The Canadian Light Source (Saskatoon, Saskatchewan) http://www.cls.usask.ca/



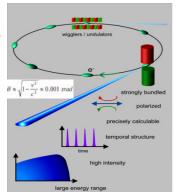
X-ray tubes



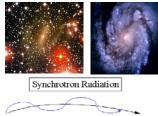
Synchrotron Radiation

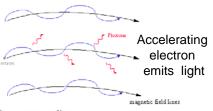
Synchrotron radiation

Synchrotron Radiation produced by relativistic electrons in accelerators (since 1947)



Natural Synchrotron Radiation





Stars and

Galaxies

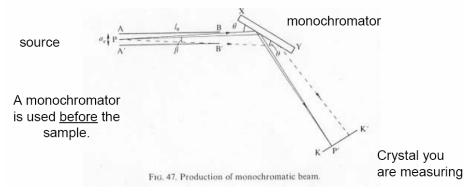
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Synchrotron radiation has a number of unique properties:

- High brightness: synchrotron radiation is extremely intense (hundreds of thousands of times higher than conventional X-ray tubes) and highly collimated.
- Wide energy spectrum: synchrotron radiation is emitted with a wide range of energies, allowing a beam of any energy to be produced.
- Synchrotron radiation is highly polarised.
- It is emitted in very short pulses, typically less that a nano-second (a billionth of a second)

HOW CAN WE SELECT A WAVELENGTH

Usually, you get a broad band of x-ray radiation from these sources. To choose a wavelength (even from a conventional source), you often find a crystal with a strong Bragg reflection and use it as a monochromator. Since the crystal will only reflect x-rays at one wavelength (or multiples of that wavelength – think about why), this method is very effective.



Closer look at the properties of Synchrotron Radiation

Synchrotron X-rays

Advantages



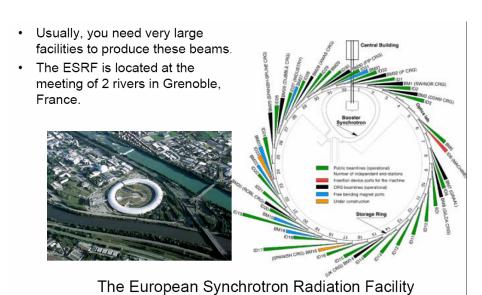
- λ_n Interatomic Spacing
- 2) High Brilliance of X-ray Sources High Resolution; Small Samples; High Degree of Coherence
- 3) No Kinematic Restrictions (E,Q uncoupled)
- 4) No Restriction on Energy Transfer that Can Be Studied

Disadvantages



- 1) Strong Absorption for Lower Energy Photons
- 2) Little Contrast for Hydrocarbons or Similar Elements
- 3) Weak Scattering from Light Elements
- 4) Radiation Damage to Samples

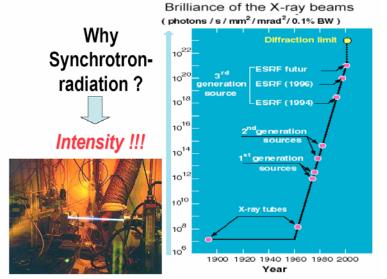
Synchrotrons



Brightness & Fluxes for Neutron & X-Ray Sources

TI TRUY BOUTES				
	Brightness $(s^{-1}m^{-2}ster^{-1})$	dE/E (%)	Divergence (mrad ²)	Flux $(s^{-1}m^{-2})$
Neutrons	10 ¹⁵	2	10×10	10^{11}
Rotating Anode	10 ²⁰	0.02	0.5×10	5×10^{14}
Bending Magnet	10 ²⁷	0.1	0.1×5	5×10 ²⁰
Undulator (APS)	10 ³³	10	0.01×0.1	10 ²⁴

Progress with Brilliance of Synchrotron Radiation



EXAMPLES of SYNCHROTRON RADIATION HIGHLIGHTS

Asp98 Wat1 nitric oxide His255 His306 His306

Complicated chemical structures

Stanford Synchrotron Radiation Lab (http://www-ssrl.slac.stanford.edu/)

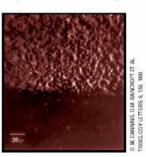


Bright x-rays can see
Low Z atoms (like hydrogen)
- Structure of complicated biomolecules

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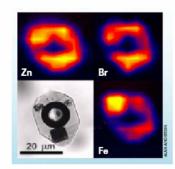
EXAMPLES of SYNCHROTRON RADIATION HIGHLIGHTS

You can use x-rays like an <u>electron microscope</u> (this isn't diffraction)



Surface of a silicon composite

Canadian Light Source



Elemental Analysis:

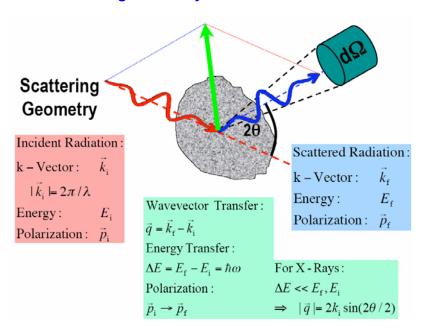
Targets absorb x-rays at certain energy levels, so by tuning the beam To these energy levels and watching how many xrays are absorbed, you can see what materials are made of.

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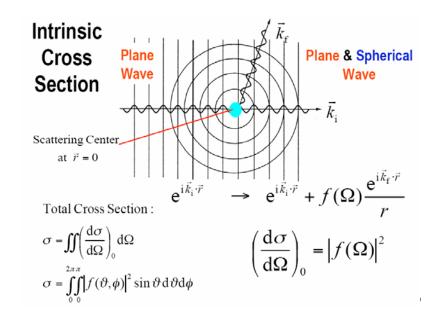
DIFFRACTION vs. SCATTERING

SCATTERING of X-rays

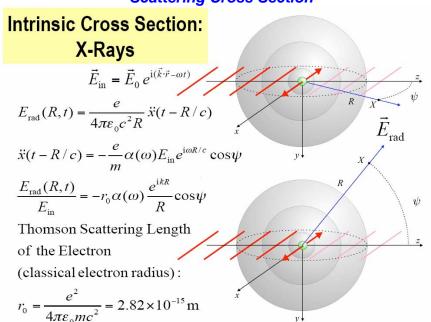
Scattering Geometry: General Consideration



Scattering Cross Section



Scattering Cross Section



Scattering by individual atoms

(Mutual interference between scattered rays gives diffraction pattern)

Scattering from atom

Consider single electron. Plane wave $E_{in} = E_0 e^{i(\mathbf{k} \cdot \mathbf{r} - \omega t)}$ $k = |\mathbf{k}| = \frac{2\pi}{\lambda}$

Scattered field: $E' = f_e \frac{E_0}{R} e^{i(kR - \omega t)}$ f_e – scattering length of electron R – radial distance

Two electrons: $E' = f_e \frac{E_0}{R} e^{ikR} \left[1 + e^{i\Delta \mathbf{k} \cdot \mathbf{r}} \right]$

or, more generally $E' = f_e \frac{E_0}{R} e^{ikR} \left[e^{i\Delta \mathbf{k} \cdot \mathbf{r}_1} + e^{i\Delta \mathbf{k} \cdot \mathbf{r}_2} \right]$

many electrons: $E' = f_e \frac{E_0}{R} e^{ikR} \sum_l e^{i\Delta \mathbf{k} \cdot \mathbf{r}_l}$ similar to single electron with $f = f_e \sum_l e^{i\Delta \mathbf{k} \cdot \mathbf{r}_l}$

intensity:
$$I \sim \left| f \right|^2 = f_e^2 \left| \sum_l e^{i\Delta \mathbf{k} \cdot \mathbf{r}_l} \right|^2$$

this is for coherent scatterers. If random then $I \sim N\!f_e^2$

Scattering length of electron: $f_e = \left[\left(1 + \cos^2 2\theta \right) / 2 \right]^{1/2} r_e$

classical electron radius $r_e = \frac{1}{4\pi\varepsilon_0} \frac{e^2}{mc^2} \approx 2.8 \times 10^{-15} \text{ m}$

In atom,
$$f_e \sum_l e^{i\Delta \mathbf{k} \cdot \mathbf{r}_l} \to f_e \int n(\mathbf{r}) e^{i\Delta \mathbf{k} \cdot \mathbf{r}_l} d^3 r$$

$$n(\mathbf{r}) - \text{electron density}$$

$$f_a = \int n(\mathbf{r})e^{i\Delta\mathbf{k}\cdot\mathbf{r}_l}d^3r$$
 - atomic scattering factor (form factor)

Atomic scattering factor (dimensionless) is determined by electronic distribution.

If $n(\mathbf{r})$ is spherically symmetric, then

$$f_a = \int_{0}^{r_0} 4\pi r^2 n(r) \frac{\sin(\Delta k \cdot r)}{\Delta k \cdot r} dr$$

in forward scattering $\Delta \mathbf{k} = 0$ so $f_a = 4\pi \int r^2 n(r) dr = Z$

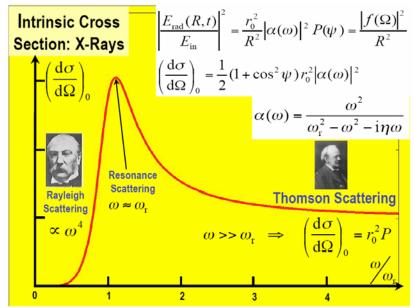
Z - total number of electrons

Atomic factor for forward scattering is equal to the atomic Z number (all rays are in phase, hence interfere constructively)

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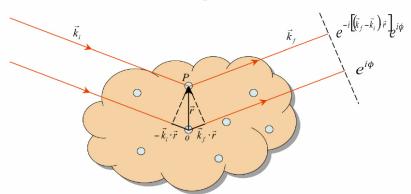
Sin θ/λ

Scattering Cross Section



What we can measure?

Adding up phases at the detector of the wavelets scattered from all the scattering centers in the sample:



Scattering

X-rays

$$\frac{d\sigma}{d\Omega} = r_0^2 \left[\frac{1 + \cos^2(2\theta)}{2} \right] S(\mathbf{q})$$

$$S(\mathbf{q}) = \langle \Sigma_{ij} \exp[-i\mathbf{q}.(\mathbf{r_i} - \mathbf{r_j})] \rangle$$

 $\{\mathbf{r_i}\}$ == electron positions.

 $\Sigma_i \exp[-i\mathbf{q}.\mathbf{r}_i] = \rho_{el}(\mathbf{q})$ Fourier Transform of electron density

And, for x-rays, $S(\mathbf{q}) = \langle \rho_{el}(\mathbf{q}) \rho_{el}^*(\mathbf{q}) \rangle$

Scattering

If electrons are bound to atoms centered on nuclei at Ri

$$\rho_{el}(\mathbf{r}) = \Sigma_{i} f_{el}(\mathbf{r} - \mathbf{R}_{i})$$

$$\rho_{el}(\mathbf{q}) = \int d\mathbf{r} \exp[-i\mathbf{q} \cdot \mathbf{r}] \Sigma_i f_{el}(\mathbf{r} - \mathbf{R}_i)$$

=
$$\Sigma_i$$
 { $\int d\mathbf{r} \exp[-i\mathbf{q}.(\mathbf{r}-\mathbf{R}_i)] f_{el}(\mathbf{r}-\mathbf{R}_i)$ } exp[-iq. \mathbf{R}_i]

=
$$f(q) \Sigma_i \exp[-iq. R_i]$$

$$= f(\mathbf{q}) \rho_{N}(\mathbf{q})$$

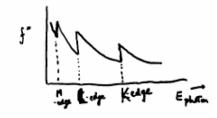
f(q) is called the Atomic Form Factor

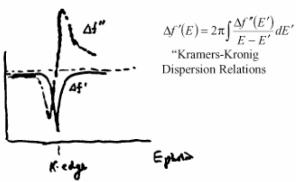
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Scattering

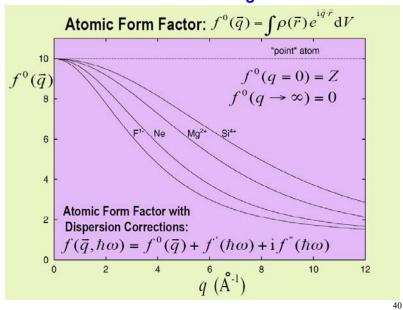
X-rays

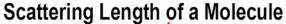
$$f = f_0 + \Delta f' + i\Delta f''$$
Scattering "anomalous" big at edges = $Zf(q)$

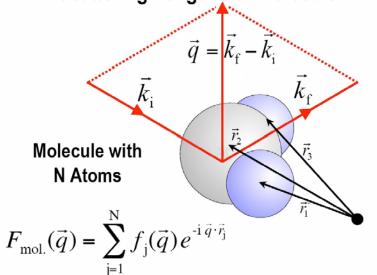


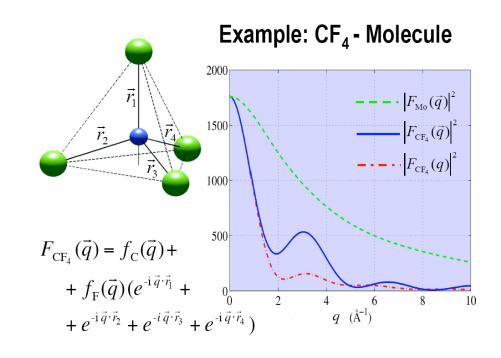


Scattering



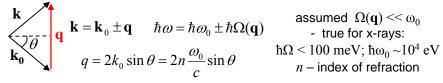






Applications of inelastic X-ray scattering: probing lattice vibrations (similar to Raman scattering)

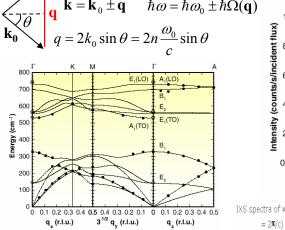
Inelastic X-ray scattering



measuring ω - ω_0 and $\sin\theta$ one can determine dispersion $\Omega(\mathbf{q})$

main disadvantage – difficult to measure ω - ω_0 accurately This difficulty can be overcome by use of **neutron scattering** Energy of "thermal" neutrons is comparable with $\hbar\Omega$ (80 meV for $\lambda{\approx}1\text{Å}$)

Inelastic X-ray scattering in GaN



Phonon dispersion of wurtzite GaN (filled circles: IXS data; solid lines: ab initio lattice-dynamical calculation.

IXS spectra of wurtzite GaN along Γ -A. Values of q_2 (in units of G_2 = $2\pi/c$) are given next to each spectrum.

Scattering from crystal

$$f_{cr} = \sum_{l} e^{i\Delta \mathbf{k} \cdot \mathbf{r}_{l}} = \sum_{l} f_{al} e^{i\Delta \mathbf{k} \cdot \mathbf{R}_{l}}$$

 \mathbf{R}_l - position of l^{th} atom, f_{al} - corresponding atomic factor

rewrite
$$f_{cr} = F \cdot S$$

where
$$F = \sum_{i} f_{aj} e^{i\Delta \mathbf{k} \cdot \mathbf{k}}$$

where $F = \sum_{i} f_{aj} e^{i\Delta \mathbf{k} \cdot \mathbf{s}_{j}}$ - structure factor of the basis, summation over the atoms in unit cell

and
$$S = \sum_{i} e^{i\Delta \mathbf{k} \cdot \mathbf{F}}$$

and $S = \sum_{l} e^{i\Delta \mathbf{k}\cdot\mathbf{R}_{l}^{c}}$ -lattice factor, summation over all unit cells in the crystal

Where
$$\mathbf{R}_l = \mathbf{R}_l^c + \mathbf{s}_i$$

Since $\Delta \mathbf{k} = \mathbf{G}$, the lattice factor becomes

$$S = \sum_{l} e^{i\mathbf{G} \cdot \mathbf{R}_{l}^{c}} = \sum_{l} e^{i2\pi m} = N$$

Then scattering intensity $I \sim |f_{cr}|^2$ where $f_{cr} = F \cdot N = N \sum_i f_{aj} e^{i\mathbf{G} \cdot \mathbf{s}_j}$

$$\mathbf{G} = \mathbf{G}_{hkl} = h\mathbf{b}_1 + k\mathbf{b}_2 + l\mathbf{b}_3 \qquad \text{if } \mathbf{s}_i = u_i\mathbf{a}_1 + v_i\mathbf{a}_2 + w_i\mathbf{a}_3$$

Then
$$F = \sum_{i} f_{aj} e^{i(u_{j}\mathbf{a}_{1} + v_{j}\mathbf{a}_{2} + w_{j}\mathbf{a}_{3})(h\mathbf{b}_{1} + k\mathbf{b}_{2} + l\mathbf{b}_{3})} = \sum_{i} f_{aj} e^{2\pi i (hu_{j} + kv_{j} + lw_{j})}$$

structure factor

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Example: structure factor of bcc lattice (identical atoms)

$$F = \sum_{i} f_{aj} e^{2\pi i (hu_j + kv_j + hw_j)}$$

Two atoms per unit cell: $\mathbf{s}_1 = (0,0,0)$; $\mathbf{s}_2 = a(1/2,1/2,1/2)$

$$F = f_a \left[1 + e^{\pi i (h+k+l)} \right]$$

 $\Rightarrow F=2f_a$ if h+k+l is even, and F=0 if h+k+l is odd Diffraction is absent for planes with odd sum of Miller indices

For allowed reflections in fcc lattice h,k,and l are all even or all odd 4 atoms in the basis.

What about simple cubic lattice?



 $\mathbf{F} = f + f \exp(2\pi i (\frac{h}{2} + \frac{k}{2} + \frac{\iota}{2}))$ $= f(1 + \exp(\pi i(h + k + l)))$

BCC structure

001 101 111 000 010

Consider the bcc lattice with single atoms at each lattice point, its unit cell can be reduced to two

identical atoms. Atom 1 is at 000 with scattering factor f, and atom 2 is at ### with a scattering

opposite to illustrate the bcc unit cell.

Click on the animation

For diffraction from a plane where the sum of h+k+l is odd, the second term is -1, so

 $\mathbf{F}_{hklodd} = f(1-1) = 0$

If h+k+l is even, the second term is +1, so

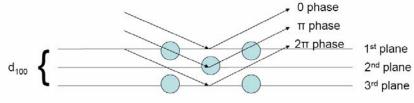
 $\mathbf{F}_{h\text{Meven}} = f(1+1) = 2f$

Thus, diffractions from bcc planes where b+k+l is odd are of zero intensity. They are forbidden reflections. These reflections are usually omitted om the reciprocal lattice.

Click on the animation opposite to illustrate the forbidden reflections

Structure factor of the BCC lattice

- What does this mean? Metallic sodium, for example, is BCC. The
 diffraction pattern does <u>not</u> contain lines such as (100), (300), (111),
 etc. whenever the sum of integers hkl is odd. However, there are
 lines such as (200), (110), (222), etc.
- The physical reason is that reflections with h+k+l= odd refer to planes of atoms where the rays are out of phase by π , so that each ray, from plane to plane, cancels out the next ray, and the net intensity is zero.
- · An example: (100) reflection in the BCC cell:



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Structure factor of the FCC lattice

 For the FCC lattice, we have the basis (identical atoms at both positions):

$$x_1 = 0 y_1 = 0 z_1 = 0$$

 $x_2 = 0 y_2 = \frac{1}{2} z_2 = \frac{1}{2}$
 $x_3 = \frac{1}{2} y_3 = 0 z_3 = \frac{1}{2}$
 $x_4 = \frac{1}{2} y_4 = \frac{1}{2} z_4 = 0$

• So, this means that F(h,k,l):

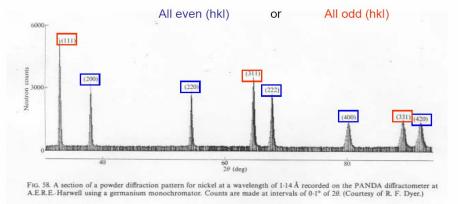
$$F(h,k,l) = f[1 + \exp(-i\pi(h+k)) + \exp(-i\pi(h+l)) + \exp(-i\pi(k+l))]$$

• Therefore, if all the indices are even integers, or all are odd F(h,k,l) = 4f. If 1 is even. and 2 are odd, then F = 0. If 1 is odd, and 2 are even, then F is zero. This means that no reflections can occur for which the indices are partly even and partly odd.

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Structure factor of the FCC lattice

· Nickel has an FCC structure:



Note: There are <u>no</u> reflections with mixtures of odd and even indices (eg. (110))

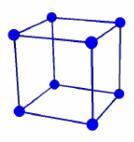
Structure factor of the SC lattice

- The structure factor F does not have to be real, because the intensity of the x-ray goes like F·F However, F·F must be real.
- For a simple cubic lattice, the structure factor is easy to calculate:

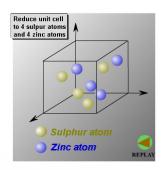
The basis is one atom, at (0, 0, 0). (This will produce all the atoms in the unit cell by translation)

$$F(h,k,l) = f(\exp 0) = 1$$

This means all of the reflections where Δk = \overline{G} are allowed (so we see all reflections of the form (hkl), eg. (100), (110), any combination of integers). We will see that this is <u>not</u> true for the BCC and FCC lattice



Structure Compound: Calculation



Structure factor calculation

Consider a general unit cell for this type of structure. It can be reduced to 4 atoms of type A at 000, 0 ##, # 0 #, # # 0 i.e. in the fcc position and 4 atoms of type B at the sites # # # from the A sites. This can be expressed as:

$$\mathbf{F} = \{f_{\mathbf{A}} + f_{\mathbf{B}}e^{\frac{\pi}{2}(h+k+l)}\}\mathbf{F}_{\text{fic}}$$

The structure factors for this structure are:

if h, k, l mixed (just like fcc) $\mathbf{F} = 4(f_{\mathbf{A}} \parallel f_{\mathbf{B}})$ if h, k, l all odd

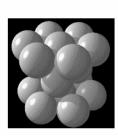
 $\mathbf{F} = 4(f_{\Delta} - f_{B})$ if h, k, l all even and h + k + l = 2n where n = odd (e.g. 200)

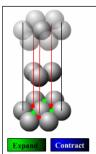
 $\mathbf{F} = 4(f_{\Delta} + f_{R})$ if h, k, l all even and h + k + l = 2n where n=even (e.g. 400)

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CPH

Close-packed hexagonal describes a way for atoms (considered as hard spheres) to pack together to fill space. The first layer (A) consists of an hexagonal array of atoms. The next layer (B) sits in the hollows of the first layer. The third layer duplicates layer A, giving an ABAB... structure. (See fcc.)



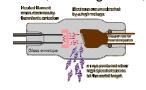


• forbidden reflections for the hcp structure occur when h+2k=3n and l is odd, where n is an integer (e.g. 113 is forbidden).

Experimental XRD techniques

Rotating crystal method -

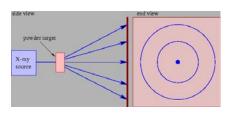
for single crystals, epitaxial films θ -2 θ , rocking curve, φ - scan





X-ray detector

Powder diffraction

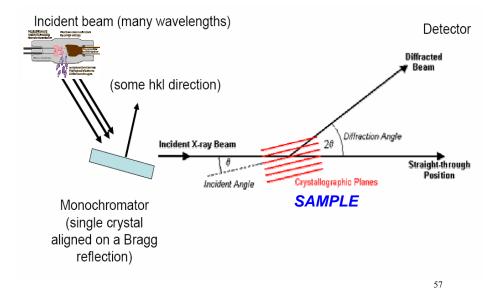


Laue method - white x-ray beam used most often used for mounting single crystals in a precisely known orientation

of X-rays

DIFFRACTION

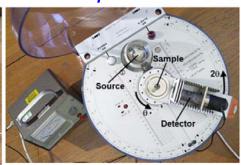
EXPERIMENTAL SETUP for Rotating Crystal Diffraction of X-rays



How are diffraction experiments done?

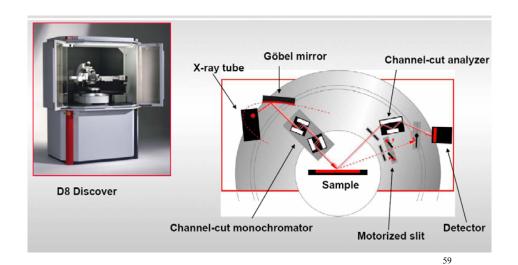
X-ray Diffraction Setup





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High Angular Resolution X-ray Diffraction Setup B11 Tiernan

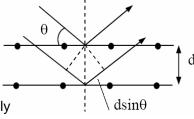


The Bragg Law

Conditions for a sharp peak in the intensity of the scattered radiation:

1) the x-rays should be specularly reflected by the atoms in one plane

2) the reflected rays from the successive planes interfere constructively



The path difference between the two x-rays: $2d \cdot \sin \theta \Rightarrow$

the Bragg formula: $2d \cdot \sin \theta = m\lambda$

The model used to get the Bragg law are greatly oversimplified (but it works!).

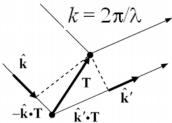
- It says nothing about intensity and width of x-ray diffraction peaks
- neglects differences in scattering from different atoms
- assumes single atom in every lattice point
- neglects distribution of charge around atoms

Diffraction condition and reciprocal lattice

Von Laue approach:

 crystal is composed of identical atoms placed at the lattice sites T

- each atom can reradiate the incident radiation in all directions.
- Sharp peaks are observed only in the directions for which the x-rays scattered from all lattice points interfere constructively.



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Consider two scatterers separated by a lattice vector \mathbf{T} . Incident x-rays: wavelength λ , wavevector \mathbf{k} ; $|\mathbf{k}| = k = 2\pi/\lambda$; $(\mathbf{k'-k}) \cdot \mathbf{T} = 2\pi m$. Assume *elastic* scattering: scattered x-rays have same energy (same λ) \Rightarrow wavevector $\mathbf{k'}$ has the same magnitude $|\mathbf{k'}| = k = 2\pi/\lambda$ $\hat{\mathbf{k}} = \frac{\mathbf{k}}{k}$ $\hat{\mathbf{k'}} = \frac{\mathbf{k'}}{k}$

Condition of constructive interference: $(\hat{\mathbf{k}}' - \hat{\mathbf{k}}) \cdot \mathbf{T} = m\lambda$ or

Define $\Delta \mathbf{k} = \mathbf{k'} - \mathbf{k}$ - scattering wave vector

Then $\Delta \mathbf{k} = \mathbf{G}$, where \mathbf{G} is defined as such a vector for which $\mathbf{G} \cdot \mathbf{T} = 2\pi m$

We got
$$\Delta \mathbf{k} = \mathbf{k'} - \mathbf{k} = \mathbf{G} \implies |\mathbf{k'}|^2 = |\mathbf{k}|^2 + |\mathbf{G}|^2 + 2\mathbf{k} \cdot \mathbf{G} \implies G^2 + 2\mathbf{k} \cdot \mathbf{G} = 0$$

 $2\mathbf{k} \cdot \mathbf{G} = G^2$ – another expression for diffraction condition

- U - another expression for diffraction condition

We obtained the *diffraction (Laue) condition*: $\Delta \mathbf{k} = \mathbf{G}$ where $\mathbf{G} \cdot \mathbf{T} = 2\pi m$

Vectors **G** which satisfy this relation form a *reciprocal lattice*

A reciprocal lattice is defined with reference to a particular Bravais lattice, which is determined by a set of lattice vectors ${\bf T}.$

Constricting the reciprocal lattice from the direct lattice:

Let $\mathbf{a_1}$, $\mathbf{a_2}$, $\mathbf{a_3}$ - primitive vectors of the direct lattice; $\mathbf{T} = n_1 \mathbf{a_1} + n_2 \mathbf{a_2} + n_3 \mathbf{a_3}$

Then reciprocal lattice can be generated using the primitive vectors

$$\mathbf{b}_1 = \frac{2\pi}{V} \mathbf{a}_2 \times \mathbf{a}_3, \ \mathbf{b}_2 = \frac{2\pi}{V} \mathbf{a}_3 \times \mathbf{a}_1, \ \mathbf{b}_3 = \frac{2\pi}{V} \mathbf{a}_1 \times \mathbf{a}_2$$

where $V = \mathbf{a_1} \cdot (\mathbf{a_2} \times \mathbf{a_3})$ is the volume of the unit cell

Then vector
$$\mathbf{G} = m_1 \mathbf{b_1} + m_2 \mathbf{b_2} + m_3 \mathbf{b_3}$$
 We have $\mathbf{b_i} \cdot \mathbf{a_j} = \delta_{ij}$ Therefore, $\mathbf{G} \cdot \mathbf{T} = (m_1 \mathbf{b_1} + m_2 \mathbf{b_2} + m_3 \mathbf{b_3}) \cdot (n_1 \mathbf{a_1} + n_2 \mathbf{a_2} + n_3 \mathbf{a_3}) = 2\pi (m_1 n_1 + m_2 n_2 + m_3 n_3) = 2\pi m$

The set of reciprocal lattice vectors determines the possible scattering wave vectors for diffraction

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We got $\Delta \mathbf{k} = \mathbf{k'} - \mathbf{k} = \mathbf{G} \implies |\mathbf{k'}|^2 = |\mathbf{k}|^2 + |\mathbf{G}|^2 + 2\mathbf{k}\cdot\mathbf{G} \implies G^2 + 2\mathbf{k}\cdot\mathbf{G} = 0$ $2\mathbf{k}\cdot\mathbf{G} = G^2$ – another expression for diffraction condition

Now, show that the reciprocal lattice vector $\mathbf{G} = h\mathbf{b_1} + k\mathbf{b_2} + l\mathbf{b_3}$ is orthogonal to the plane represented by Miller indices (hkl)

plane (hkl) intercepts axes at points x, y, and z given in units a_1 , a_2 and a_3

By the definition of the Miller indices:

$$(h,k,l) = \left(\frac{1}{x}, \frac{1}{y}, \frac{1}{z}\right)$$

 \mathbf{a}_{3} \mathbf{a}_{2} \mathbf{v} \mathbf{v}

define plane by two non-collinear vectors ${\bf u}$ and ${\bf v}$ lying within this plane:

$$\mathbf{u} = y\mathbf{a}_2 - x\mathbf{a}_1$$
 and $\mathbf{v} = y\mathbf{a}_2 - z\mathbf{a}_3$

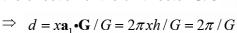
prove that G is orthogonal to u and v:

$$\mathbf{u} \cdot \mathbf{G} = (y\mathbf{a}_2 - x\mathbf{a}_1) \cdot (h\mathbf{b}_1 + k\mathbf{b}_2 + h\mathbf{b}_3) = 2\pi(yk - xh) = 0$$

analogously show $\mathbf{v} \cdot \mathbf{G} = \mathbf{0}^{-63}$

Now, prove that the distance between two adjacent parallel planes of the direct lattice is $d = 2\pi/G$.

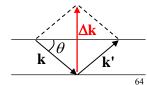
The interplanar distance is given by the projection of the one of the vectors $x\mathbf{a}_1$, $y\mathbf{a}_2$, $z\mathbf{a}_3$, to the direction normal to the (*hkl*) plane, which is the direction of the unit vector \mathbf{G}/G



The reciprocal vector G(hkl) is associated with the crystal planes (hkl) and is normal to these planes. The separation between these planes is $2\pi/G$

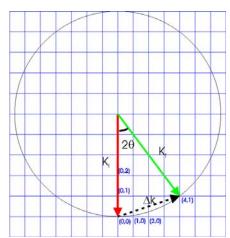
$$2\mathbf{k} \cdot \mathbf{G} = G^2 \Rightarrow 2|\mathbf{k}| \operatorname{Gsin} \theta = G^2$$
$$\Rightarrow 2 \cdot 2\pi \sin \theta / \lambda = 2\pi / d \Rightarrow 2d \sin \theta = \lambda$$

 $2d\sin\theta = m\lambda$ - get Bragg law



Ewald Construction for Diffraction

Condition and reciprocal space



Diffraction occurs for:

$$\overrightarrow{k} + \overrightarrow{G} = \overrightarrow{k}'$$

$$\overrightarrow{Or}$$

$$\overrightarrow{k'} - \overrightarrow{k} = \overrightarrow{G}$$

$$k = 2\pi/\lambda$$

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Bragg plane

Geometric interpretation of Laue condition:

$$2\mathbf{k} \cdot \mathbf{G} = G^2 \Rightarrow \mathbf{k} \cdot \left(\frac{1}{2}\mathbf{G}\right) = \left(\frac{1}{2}\mathbf{G}\right)^2$$
Bragg plane

$$\frac{1}{2}|\bar{\mathbf{G}}|$$

$$\mathbf{K}$$
Bragg plane
$$\frac{1}{2}|\bar{\mathbf{G}}|$$
Bragg plane

- Diffraction is the strongest (constructive interference) at the perpendicular bisecting plane (Bragg plane) between two reciprocal lattice points.
- true for any type of waves inside a crystal, including electrons.
- Note that in the original real lattice, these perpendicular bisecting planes are the planes we use to construct Wigner-Seitz cell

Geometric interpretation of Laue condition:

$$2\mathbf{k} \cdot \mathbf{G} = G^2 \Rightarrow \mathbf{k} \cdot \left(\frac{1}{2}\mathbf{G}\right) = \left(\frac{1}{2}\mathbf{G}\right)^2$$

From the Laue condition, a different condition for diffraction can be derived. It is again equivalent to both Laue and Bragg

k' - k = G and so k' = G + k

Taking the dot product of both sides,

 $(k' \bullet k') = (G + k) \bullet (G + k)$

Hence $\mathbf{k'} \cdot \mathbf{k'} = \mathbf{G} \cdot \mathbf{G} + 2\mathbf{G} \cdot \mathbf{k} + \mathbf{k} \cdot \mathbf{k}$

But the magnitudes of k and k' are equal so k' • k' and k • k cancel.

Hence $2\mathbf{G} \cdot \mathbf{k} = -\mathbf{G} \cdot \mathbf{G}$

If there is a reciprocal lattice point at the position G there is also one at -G so the minus sign is unnecessary

Hence **k** • ½**G** = |½**G** |²



 $\frac{1}{2}|\bar{G}|$